

N-channel TrenchMOS standard level FET

Rev. 3 — 13 October 2010

Product data sheet

Product profile 1.

1.1 General description

Standard level N-channel enhancement mode Field-Effect Transistor (FET) in a plastic package using Nexperia High-Performance Automotive (HPA) TrenchMOS technology. This product has been designed and qualified to the appropriate AEC standard for use in automotive critical applications.

1.2 Features and benefits

- Q101 compliant
- Suitable for standard level gate drive sources

1.3 Applications

- 12 V, 24 V and 42 V loads
- Automotive systems
- DC-to-DC converters
- Engine management

1.4 Quick reference data

Table 1. Quick reference data

Symbol Parameter Conditions Min Unit Тур Max T_i ≥ 25 °C; T_i ≤ 175 °C V V_{DS} drain-source 100 voltage I_D drain current V_{GS} = 10 V; T_{mb} = 25 °C; 24.8 A see Figure 1; see Figure 4 P_{tot} total power T_{mb} = 25 °C; see Figure 2 85 W _ dissipation **Static characteristics** drain-source $V_{GS} = 10 \text{ V}; I_{D} = 10 \text{ A};$ 40 53 mΩ R_{DSon} T_i = 25 °C; see <u>Figure 12</u>; on-state resistance see Figure 13

Suitable for thermally demanding environments due to 175 °C rating

- General purpose power switching
- Solenoid drivers
- Transmission control



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Table 1. Quick reference datacontinued							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Avalanche ruggedness							
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	$ \begin{split} I_D &= 24.8 \text{ A}; \ V_{sup} \leq 100 \text{ V}; \\ R_{GS} &= 50 \ \Omega; \ V_{GS} = 10 \text{ V}; \\ T_{j(init)} &= 25 \ ^\circ\text{C}; \ unclamped \end{split} $		-	-	81	mJ
Dynamic characteristics							
Q_{GD}	gate-drain charge	$I_D = 10 \text{ A}; V_{DS} = 80 \text{ V};$ $V_{GS} = 10 \text{ V}; \text{ see } Figure 14$		-	8.5	-	nC

2. Pinning information

Table 2.Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	С	source		-
2	S	source	mb	
3	S	source		
4	G	gate	Q	
mb	D	mounting base; connected to drain		mbb076 S
			SOT669 (LFPAK)	

3. Ordering information

Table 3.	Ordering in	formation		
Type number		Package		
		Name	Description	Version
BUK7Y53-1	00B	LFPAK	plastic single-ended surface-mounted package (LFPAK); 4 leads	SOT669

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4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

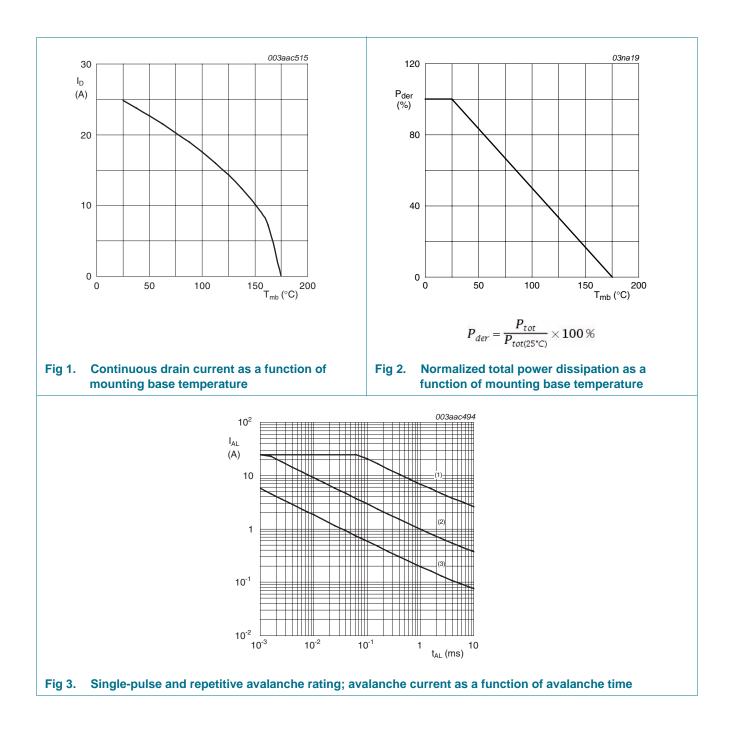
Max 100	Unit V V
400	V
100	-
20	V
24.8	A
17.6	А
99	A
85	W
175	°C
175	°C
24.8	А
99	А
81	mJ
-	J
_	99

[1] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

[2] Repetitive avalanche rating limited by an average junction temperature of 170 °C.

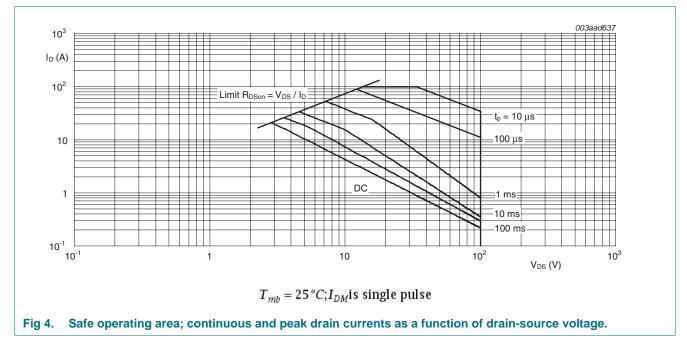
[3] Refer to application note AN10273 for further information.

BUK7Y53-100B



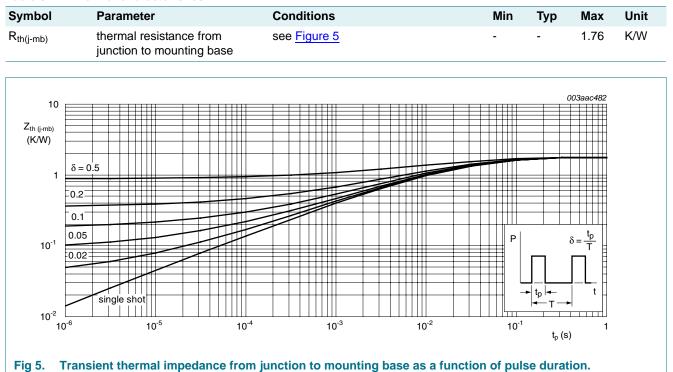
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5. Thermal characteristics

Table 5.Thermal characteristics



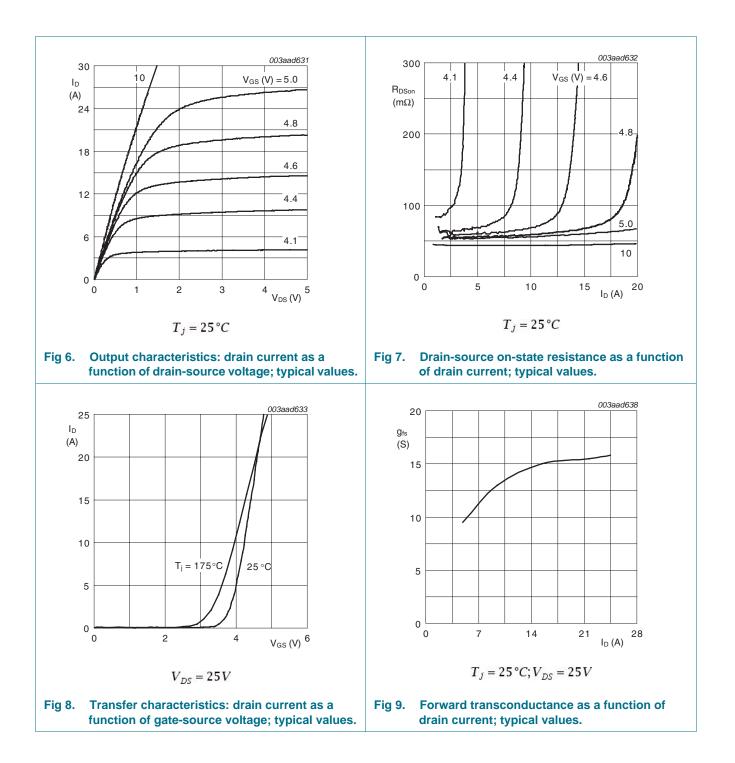
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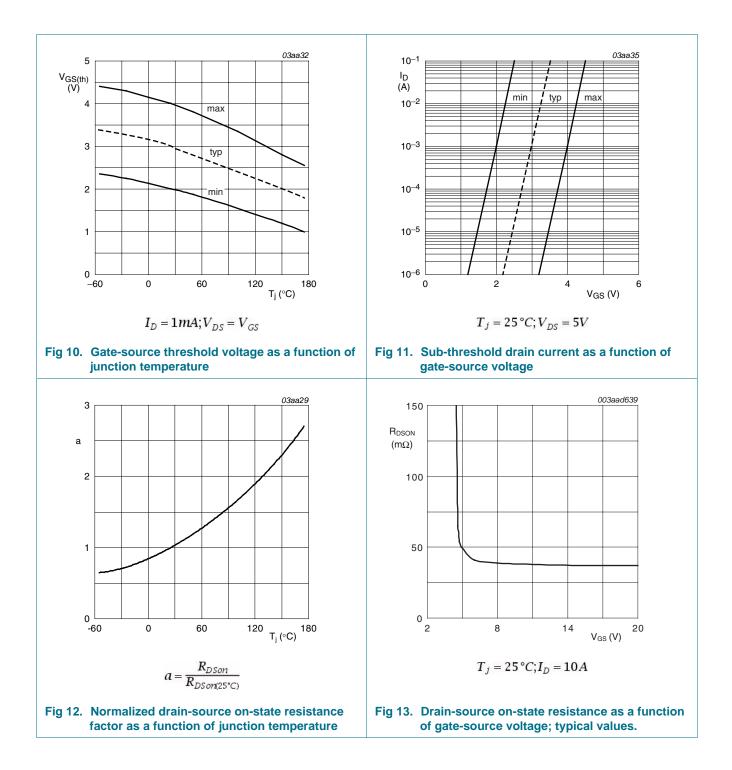
6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	octeristics					
V _{(BR)DSS} drain-source		I _D = 250 μA; V _{GS} = 0 V; T _i = 25 °C	100	-	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _i = -55 °C	90	-	-	V
V _{GS(th)}	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C};$ see <u>Figure 10</u> ; see <u>Figure 11</u>	2	3	4	V
		I _D = 1 mA; V _{DS} = V _{GS} ; T _j = -55 °C; see <u>Figure 10</u>	-	-	4.4	V
		I _D = 1 mA; V _{DS} = V _{GS} ; T _j = 175 °C; see <u>Figure 10</u>	1	-	-	V
I _{DSS}	drain leakage current	V_{DS} = 100 V; V_{GS} = 0 V; T_j = 25 °C	-	0.02	1	μΑ
		V_{DS} = 100 V; V_{GS} = 0 V; T_j = 175 °C	-	-	500	μΑ
I _{GSS}	gate leakage current	$V_{DS} = 0 \text{ V}; V_{GS} = 20 \text{ V}; T_j = 25 \text{ °C}$	-	2	100	nA
		$V_{DS} = 0 \text{ V}; V_{GS} = -20 \text{ V}; T_j = 25 \text{ °C}$	-	2	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 10 A; T _j = 175 °C; see <u>Figure 12</u> ; see <u>Figure 13</u>	-	-	138	mΩ
		V _{GS} = 10 V; I _D = 10 A; T _j = 25 °C; see <u>Figure 12</u> ; see <u>Figure 13</u>	-	40	53	mΩ
Dynamic ch	aracteristics					
Q _{G(tot)}	total gate charge	$I_D = 10 \text{ A}; V_{DS} = 80 \text{ V}; V_{GS} = 10 \text{ V};$	-	22	-	nC
Q _{GS}	gate-source charge	see Figure 14	-	4.3	-	nC
Q _{GD}	gate-drain charge		-	8.5	-	nC
C _{iss}	input capacitance	$V_{GS} = 0 V; V_{DS} = 25 V; f = 1 MHz;$	-	1100	1467	pF
C _{oss}	output capacitance	$T_j = 25 \text{ °C}; \text{ see } Figure 15$	-	142	170	pF
C _{rss}	reverse transfer capacitance		-	63	86	pF
d(on)	turn-on delay time	V_{DS} = 30 V; R_L = 3 Ω ; V_{GS} = 10 V;	-	15.3	-	ns
t _r	rise time	$R_{G(ext)} = 10 \ \Omega$	-	7.8	-	ns
d(off)	turn-off delay time		-	34	-	ns
f	fall time		-	7.7	-	ns
Source-drai	in diode					
V _{SD}	source-drain voltage	I _S = 15 A; V _{GS} = 25 V; T _j = 25 °C; see <u>Figure 16</u>	-	0.85	1.2	V
t _{rr}	reverse recovery time	$I_{S} = 20 \text{ A}; \text{ d}I_{S}/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$	-	56	-	ns
Q _r	recovered charge	$V_{DS} = 30 V$	-	155	-	nC

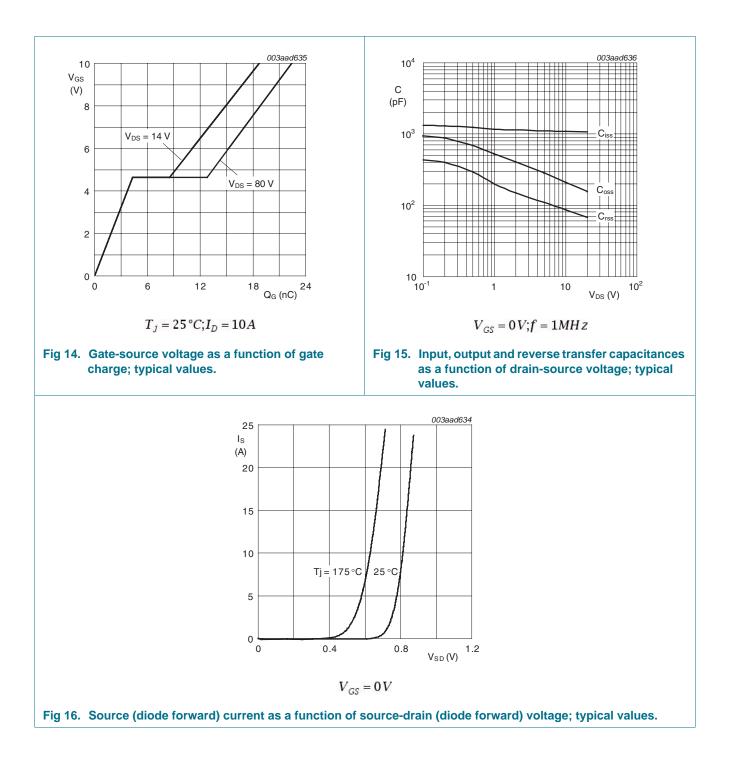
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7. Package outline

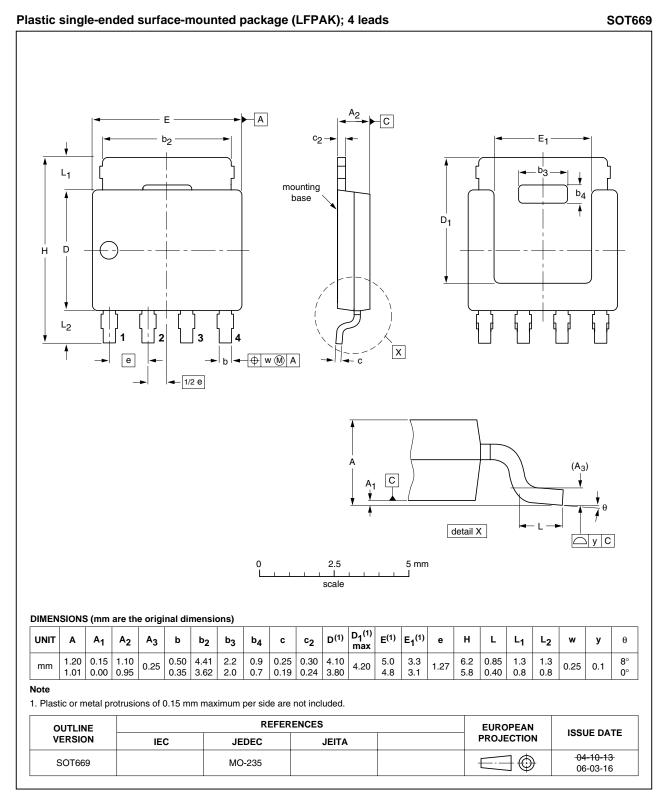


Fig 17. Package outline SOT669 (LFPAK)

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BUK7Y53-100B

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8. Revision history

Table 7. Revision I	history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BUK7Y53-100B v.3	20101013	Product data sheet	-	BUK7Y53-100B_2
Modifications:	 Status change 	d from objective to product.		
BUK7Y53-100B_2	20100211	Objective data sheet	-	BUK7Y53-100B_1

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9. Legal information

9.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

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